NSN 5962-01-388-7528

Memory Microcircuit - Page 1 of 1

AeroBase Group

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Body Length:

0.250 inches

Body Width:

0.937 inches

Maximum Power Dissipation Rating:

1.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

20.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

55.00 nanoseconds read-write cycle

Memory Device Type:

Ram

Hybrid Technology Type:

Monolithic

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

18 printed circuit

Specification Data:

81349-mil-m-38510 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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